

## Irradiation Effect on the Electric and Magnetic Properties of Two - Dimensional Organic Complexes

Thesis

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То

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## Summary

The present work is concerned mainly with studying the electric and magnetic interaction in diammine complexes  $(C_2H)_n(NH_3)MCl_{4-x}$  Br, where n = 3, 6, 9, 12, M = Cu<sup>2+</sup>, Mn<sup>2+</sup>, Co<sup>2+</sup> and x= 0, 1, 2 before and after  $\gamma$ -irradiation with different doses. From the plot of  $\varepsilon_r$  as a function of T, the phase transitions and the polarization mechanisms were identified for each sample. Moreover, from In ( $\sigma$ ) versus the temperature the activation energies at different temperature regions are deduced. Also, from In ( $\sigma$ ) versus frequency, the conduction mechanisms were determined. Graphical representation of dielectric data by means of Cole-Cole ( $\varepsilon''/\varepsilon'$ ) at selected temperatures were plotted and the relaxation arc times for most test samples were deduced.

The molar magnetic susceptibility  $(\chi_M)$  of the complexes under test were measured in the temperature range from 78 K up to 500 K and at different magnetic field strengths (2.10, 2.46, 2.79 kOe) by using Gouy's method. The least square fits for the reciprocal of the molar magnetic susceptibility versus temperature at different magnetic field strengths gave the magnetic parameters [ $\theta$ , C,  $\mu_{eff}$  and (J/kB)].

In order to identify the type of charge carriers responsible for the conduction process, the thermoelectric power was measured for the samples using the differential technique in the temperature range (300-500 K).

Before Irradiation the dielectric constant E was found to be affected by varying the length of the hydrocarbon chain embedded between the metallic layers of the complexes For the complexes  $(CH_2),(NH_3)_2CoCl_4$ ; n = 3, 6, 9, 12,  $\varepsilon_r$  was found to have larger values for the complexes with odd number of carbon atoms (n = 3, 9) than those containing even number (n= 6, 12). This is due to the existence of permanent dipoles in the complexes with odd n only. Moreover, it is found that, the complex with n =3 has  $\varepsilon_r$  values larger than those of the complex with n= 9, this can be attributed to the difference in the molecular size. while for the complexes with even n, the complex with larger molecule (n=12) has larger electronic polarization component and consequently larger values of  $\varepsilon_r$ .

Also,  $\varepsilon_r$  was found to be affected by varying the metallic ion located at the center of the octahedron. For the complex NDAMCI<sub>4</sub>, where the divalent metal ion M=Mn, Co<sup>2+</sup> and Cu<sup>2+</sup>,  $\varepsilon_r$  decreases with increasing the electronegativity of the divalent metal 1on. It is also noticeable that, as the radius of the metallic ion increases, the peak position shifts towards the higher temperature side and the peak values decreases. This was explained in the light of the molecules size and their packing together.

Moreover,  $\varepsilon_r$  was affected by changing the halogen ion. For the complex PDAMnCl<sub>4-x</sub>Br<sub>x</sub> where x=0, 1 and 2, it was found that,  $\varepsilon_r$  increases by increasing x. This was ascribed to the difference in both of the electronegativity and atomic number of the two halides.

The temperature dependence of a.c conductivity, In ( $\sigma$ ), for the complex (CH<sub>2</sub> (NH<sub>3</sub>)<sub>2</sub>CoCl<sub>4</sub>; n = 3, 6, 9. 12, revealed two distinct regions. At the low temperature region (300-390 K), In ( $\sigma$ ) decreases with increasing carbon atoms as a result of decreasing the bridging between layers. While, at the high temperature region (390-500 K), the rotation NH<sub>3</sub> groups between the metallic layers increases and as a result the paths of interaction decrease which increase In ( $\sigma$ ) with increase the carbon atoms.

The effect of changing the divalent metal ion on the temperature dependence of ln ( $\sigma$ ) for the complex NDAMCL<sub>4</sub>; M= Mn<sup>2+</sup>, Co<sup>2+</sup> and Cu<sup>2+</sup>, shows six distinct regions (I- VI), in the first temperature region I (300-379 K), the conductivity increases by decreasing the ionic radius. In the remainder temperature region (II-VI) (379-520 K), there is no definite general trend for the temperature dependence of In ( $\sigma$ ). Increasing of temperature causes an increase in the lattice dimensions on one hand and weakening the hydrogen bond on the other hand. The first effect results a decrease in In ( $\sigma$ ) while the latter results a increase in In ( $\sigma$ ). It was found also that, the complex containing Cu<sup>2+</sup> has the highest values of In ( $\sigma$ ) since Cu<sup>2+</sup> has the largest value of electronegativity compared with to other two metal ions.

For the complex PDAMnCl<sub>4-x</sub> Br<sub>x</sub>; x=0, 1 and 2, it was found from comparing In (a complexes with x=0 and x=2, that the values of In ( $\sigma$ ) in case of B<sup>-1</sup> ion are larger than those in case of Cl<sup>-1</sup>. The difference in the electronegativity of the halide behavior of the two ions is the main factor affecting the strength of the H-bond. Also, it was found that, the size of the halide ion plays the major role in the values of In ( $\sigma$ ). However, in the case of complex with x=1, In ( $\sigma$ ) generally has values less than those of the complex with x=2 and larger than that of the complex with x=0. By comparing E<sub>a</sub> of the three complexes, one finds that E<sub>a</sub> of complex with x=1 is the highest one. This is ascribed to the presence of one nonbonding axial Br<sup>-1</sup> ion which leads to more structure asymmetry.

Upon determining the influence of changing interlayer separation on the temperature dependence of  $\chi_M$  for the complex in the form  $(CH_2)_n(NH_3)_2CoC_4$ , n= 3,6,9 at H- 2.10 kOe, it was found that,  $\chi_M$  for the complex with n= 3 has the highest values while the complex n =6 has the lowest values. As n increases, the distances between with the successive metallic layers increase. This results in a decrease in the ferromagnetic interaction component which in turn increases the antiferromagnetic component and thereby decreases  $\chi_M$ . Moreover, the complex with n =6 which does not contain canted antiferromagnetic behavior has a stronger antiferromagnetic interaction which is responsible for the lowest values of  $\chi_M$ . The magnetic susceptibility  $\chi_M$  of the complex was affected by varying the divalent metal ion. For the complex NDAMCI<sub>4</sub>, M= Mn<sup>2+</sup>, Co<sup>2+</sup> and Cu<sup>2+</sup>,  $\chi_M$  was measured as a function of temperature and at H = 2.10, 2.46 and 2.79 kOe. It was found that, for the two antiferromagnetic complexes containing metal ions Mn<sup>2+</sup> and Co<sup>2+</sup>, the complex with Mn<sup>2+</sup> have  $\chi_M$  values, larger than those of complex with Co<sup>2+</sup>. This could be attributed the spin quantum number s. In case of the ferromagnetic complex NDACuCl<sub>4</sub>, XM has the smallest values since s= 1/2 for Cu<sup>2+</sup>.

The irradiation process causes three different effects in our investigated complexes. the first one is the ionization of the metal ions  $M^{2+}$  and change their valency to  $M^{3+}$  resulting in a large number of free electrons and thereby increasing In ( $\sigma$ ). Moreover, the change of valency is accompanied by a decrease in the ionic radii that result in an additional increase in In ( $\sigma$ ). Secondly, it disorders the lattice (i.e. creates lattice defects). each resulting from an ion shift from one site to another. The formation of the lattice defects is reflected as an increase in e and decrease in In ( $\sigma$ ). Thirdly, the  $\gamma$ -rays causes rupture of some bonds, thereby decrease or increase the number of electric dipoles per unit volume. This depends on the energy of the  $\gamma$ -dose, if this energy is sufficient to rupture the weak H-bond only it will cause a decrease in the number of dipoles, while if it is enough to rupture the backbone bonds, then the number of dipoles will be increased. The rupture process, leads to an increase in the electrons which in turn increase In ( $\sigma$ ).

For the complex PDACoCl<sub>4</sub>,  $\varepsilon_r$  values at dose = 3 M Rad lie in between the corresponding values of 1 and 2 M Rad. This could be due to the energy of  $\gamma$ -rays being sufficient to rupture the weak H-bonds and as a result  $\varepsilon_r$  increases are less than the corresponding increases in the case of 2 M Rad At 4 M Rad, the energy of  $\gamma$ -rays becomes capable of breaking the covalent backbone bonds and this in turn increase  $\varepsilon_r$ .

For the complex NDAMnCI<sub>4</sub>, the highest values of  $\varepsilon_r$  are obtained at 1 M Rad due to the ionization of Mn<sup>2+</sup> ion and changing its valency. According to Jahn-Teller theory, this change transforms the symmetric octahedral structure to asymmetric tetragonally distorted octahedron and as a result e increased. As the irradiation dose is increased to 2 and 3 M Rad,  $\varepsilon_r$  decreases and the broad hump observed is divided into two displacive humps at about 376 and 422 K (corresponding to 2 M Rad). This can be explained by considering, the relatively high energy of  $\gamma$ -rays becomes able to break some of the weak H-bonds which decrease  $\varepsilon_r$ . At 4 M Rad, the energy of  $\gamma$ -ray, ruptures the bonds of the hydrocarbon chain, this in turn increase  $\varepsilon_r$ .

For the complex PDACuCl<sub>4</sub>, it was found that,  $\varepsilon_r$  increases with increasing the irradiation dose as general trend. The  $\gamma$  radiation ionizes the divalent metal ion Cu<sup>2+</sup> changing its valency into Cu<sup>3+</sup>, but Cu<sup>3+</sup> ions in the complex are usually reduced (i.e. become Cu<sup>2+</sup> ions again by heating), In addition the two

other effects of  $\gamma$ -irradiation mentioned before are still present. At 1 M Rad, the effect of formation of structure defects cancels that of the H-bond rupture and no change in  $\varepsilon_r$  is detected. At higher doses (2, 3 and 4 M Rad), the formation of structure defects become the predominant factor.

From the results of In ( $\sigma$ ) obtained for the irradiated complex PDACOC1<sub>4</sub>, it was found that, in the temperature region I (300-335 K). when the complex is irradiated by 1, 2 and 3 M Rad, the first and second effects are present but the ionization effect is the predominant one and therefore, In ( $\sigma$ ) increases by increasing the dose. For the complexes irradiated by 4 M Rad dose, scission of the backbone bonds occurred causing further increase in In ( $\sigma$ ). The same explanation applies to explain the behavior of In ( $\sigma$ ) in the region II (330-445 K) except that, the values of In ( $\sigma$ ) at 3 M Rad dose are slightly lower than the values of ( $\sigma$ ) at 2 M Rad dose. This may be ascribed to the larger formation of defects, For temperatures above 445 K, In ( $\sigma$ ) becomes thermally activated and as a result increase In ( $\sigma$ ). As the  $\gamma$ rays dose increases, the probability for the complex to form defects (by heating) becomes lower and as a result In ( $\sigma$ ) decreases by increasing  $\gamma$ -doses.

Comparison between the temperature dependence of In ( $\sigma$ ) for the unirradiated and irradiated complex NDAMnCl<sub>4</sub> shows that, In ( $\sigma$ ) exhibits four different temperature regions (1-IV) with different activation energies. At 1 M Rad, the first effect (ionization of the metal ions) is predominant and so In ( $\sigma$ ) has the highest values. As  $\gamma$ -dose is increased to 2 and 3 M Rad respectively, the second factor (formation of the lattice defects) becomes more effective and thus In ( $\sigma$ ) decreases. At 4 M Rad, In ( $\sigma$ ) increases again. This increase may be due to the increasing of the energy of  $\gamma$ -ray dose which causes rupture of the covalent backbone bonds, which in turn increases In ( $\sigma$ ) again.

The results of effects on In ( $\sigma$ ) for irradiated complex PDACuCl<sub>4</sub> indicated that, In ( $\sigma$ ) is affected by the irradiation doses only in the temperature region (300-375 K). At 1 M Rad, the energy of  $\gamma$ irradiation is sufficient to ionize Cu<sup>2+</sup> ions and change their valence to Cu<sup>3+</sup> and this in turn increases In ( $\sigma$ ). At 2 M Rad, the  $\gamma$ -irradiation forms lattice defects that decrease In ( $\sigma$ ). More increase in the dose of  $\gamma$ -rays (3 and 4 M Rad), caused scission in some backbone bonds and as a result increased In ( $\sigma$ ) again. Beyond 375 K, In ( $\sigma$ ) as a function of T shows no detectable change in its values by irradiation doses. This is ascribed to the fact that, the complex containing Cu<sup>3+</sup> is unstable and immediately returns to the more stable Cu<sup>2+</sup> complex. The ionizing effect which is associated with  $\gamma$ -irradiation becomes ineffective in this case. Now, only two remainder effects of the  $\gamma$ -irradiation exist. the first one is the formation of lattice defects which causes a reduction in In ( $\sigma$ ) and the second one is the scission of some bonds which